

# CFEXPIESS 3TE8 Series

Customer:	
Customer	
Part Number:	
Innodisk	
Part Number:	
Innodisk	
<b>Model Name:</b>	
Date:	

Innodisk	Customer		
Approver	Approver		

# Total Solution For Industrial Flash Storage



### **Features:**

- PCIe Gen 3 x2, NVMe SSD
- Kioixa 3D TLC NAND
- Standard temperature
- iPower Guard
- iData Guard
- Dynamic Thermal Management
- Hybrid Write Mode with SLC Cache Enable
- Support TCG OPAL function

### **Performance:**

- Sequential Read up to 1,750 MB/s
- Sequential Write up to 1,600 MB/s

### **Power Requirements:**

Input Voltage:	3.3V± 5%
Max Operating Wattage (R/W):	2.8W
Idle Wattage:	0.9W

### **Reliability:**

Capacity	TBW (Client)	DWPD
128GB	86	0.7
256GB	192	0.8
512GB	361	0.5
1TB	803	0.5

Data Retention	1 Year		
Warranty	3 Years		

<sup>1</sup> year data retention is at NAND life end.

For warranty details, please refer to:

https://www.innodisk.com/en/support\_and\_service/warranty



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TPS, Apr., 2025



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## **REVISION HISTORY**

Revision	Description	Date
V1.0	First Release	Nov., 2024
V1.1	Update Transfer Mode	Jan., 2025
V1.2	Remove WT Information	Apr., 2025



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### 1. Product Overview

### 1.1 Introduction of Innodisk CFexpress 3TE8

Innodisk CFexpress 3TE8 is a NVM Express DRAM-less SSD designed with PCIe interface and industrial 3D TLC NAND Flash. CFexpress 3TE8 supports PCIe Gen 3 x2 and it is compliant with NVMe 1.4 providing excellent top and also sustained performance. With sophisticated error detection and correction (ECC) functions, the module can provide full End-to-end Data Path Protection that secures the data transmission between the host system and NAND Flash.

Innodisk CFexpress 3TE8 is designed with AES engine, which is a built in controller. When controller receives the data package from host, AES engine encrypts the data package and saves the encrypted data into NAND flash. Thus, unauthorized personal has no access to decrypt the data in NAND flash.

### 1.2 Product View and Models

Innodisk CFexpress 3TE8 is available in follow capacities with industrial 3D TLC flash ICs.

CFexpress 3TE8 128GB

CFexpress 3TE8 256GB

CFexpress 3TE8 512GB

CFexpress 3TE8 1TB



Figure 1: Innodisk CFexpress 3TE8

### 1.3 PCIe Interface

Innodisk CFexpress 3TE8 supports PCIe Gen 3 interface and compliant with NVMe 1.4. CFexpress 3TE8 can work under PCIe Gen 1, Gen 2 and Gen 3.

Most of operating system includes NVMe in-box driver now. For more information about the driver support in each OS, please visit <a href="https://nvmexpress.org/drivers/">https://nvmexpress.org/drivers/</a>.



# 2. Product Specifications

### 2.1 Capacity and Device Parameters

CFexpress 3TE8 device parameters are shown in Table 1.

**Table 1: Device parameters** 

Capacity	Cylinders	Heads	Sectors	LBA	User Capacity(MB)
128GB				234441648	114473
256GB	4.6202	4.5		468862128	228937
512GB	16383	16383 16 63	63	937703088	457863
1TB				1875385008	915715

### 2.2 Performance

Burst Transfer Rate: 2 GB/s

Table 2: Performance- 112 Layers 3D TLC

Capacity	Unit	128GB	256GB	512GB	1TB
Sequential*		1,500	1,750	1,750	1,750
Read (Q8T1)		1,300	1,730	1,730	1,730
Sequential*		FF0	1 150	1 600	1.600
Write (Q8T1)	MB/s	550	1,150	1,600	1,600
Sustained					
Sequential Read		690	970	1,100	1,050
(Avg.)***					
Sustained					
Sequential Write		170	340	480	430
(Avg.)***					
4KB Random**		F7 000	116 000	422.000	427.000
Read (Q32T16)	IODC	57,000	116,000	423,000	437,000
4KB Random**	IOPS	127.000	226,000	204.000	200,000
Write (Q32T16)		127,000	236,000	304,000	299,000

Note: \* Performance results are 3TE8 with Kioxia BiCS5 NAND composition measured in Room Temperature with Out-of-Box devices and may vary depending on overall system setup. In addition, 3TE8 series adopt hybrid mode which enables SLC cache followed by TLC direct write to strike balance between burst performance and steady overall stability.

Note: \*\* Performance results are based on CrystalDiskMark 8.0.1 with file size 1000MB. Unit of 4KB item is IOPS.

Note: \*\*\* Performance results are based on AIDA 64 v5.98 with block size 1MB of Linear Read & Write Test Item.



### 2.3 Electrical Specifications

### 2.3.1 Power Requirement

**Table 3: Innodisk CFexpress 3TE8 Power Requirement** 

Item	Symbol	Rating	Unit
Input voltage	V <sub>IN</sub>	+3.3 DC +- 5%	<b>V</b>

### 2.3.2 Power Consumption

**Table 4: Power Consumption** 

Mode	Power Consumption (W)
Read	3.0
Write	2.7
Idle	0.6
Power-on peak	5.0

Target: CFexpress 3TE8 1TB

Note: Current results may vary depending on system components and power circuit design. Please refer to the test report for other capacities.

### 2.4 Environmental Specifications

### 2.4.1 Temperature Ranges

**Table 5: Temperature range for CFexpress 3TE8** 

Temperature Range	
Operating	Standard Grade: 0°C to +70°C
Storage	-40°C to +85°C

### 2.4.2 Humidity

Relative Humidity: 10-95%, non-condensing

### 2.4.3 Shock and Vibration

Table 6: Shock/Vibration Testing for CFexpress 3TE8

Reliability	Test Conditions	Reference Standards
Vibration	7 Hz to 2K Hz, 20G, 3 axes	IEC 60068-2-6
Mechanical Shock	Duration: 0.5ms, 1500 G, 3 axes	IEC 60068-2-27



### 2.4.4 Mean Time between Failures (MTBF)

Table 7 summarizes the MTBF prediction results for various CFexpress 3TE8 configurations. The analysis was performed using a RAM Commander<sup>™</sup> failure rate prediction.

- **Failure Rate**: The total number of failures within an item population, divided by the total number of life units expended by that population, during a particular measurement interval under stated condition.
- **Mean Time between Failures (MTBF)**: A basic measure of reliability for repairable items: The mean number of life units during which all parts of the item perform within their specified limits, during a particular measurement interval under stated conditions.

**Table 7: CFexpress 3TE8 MTBF** 

Product	Condition	MTBF (Hours)
Innodisk CFexpress 3TE8	Telcordia SR-332 GB, 25°C	>3,000,000

### 2.5 CE and FCC Compatibility

CFexpress 3TE8 conforms to CE and FCC requirements.

**Table 8: CFexpress 3TE8 ESD** 

Reliability	Reference standards
Electrostatic Discharge (ESD)	IEC 61000-4-2 ESD

### 2.6 RoHS Compliance

CFexpress 3TE8 is fully compliant with RoHS directive.



### 2.7 Reliability

**Table 9: CFexpress 3TE8 TBW** 

Parameter	Value	
Read Cycles	Unlimited Read Cycles	
Flash endurance	3,000 P/E cycles	
Error Correct Code	Support(LDPC)	
Data Retention	Under 40°C:	
	1 Year at NAND Life End	
TBW* (Total Bytes W	<b>ritten)</b> Unit: TB	
Capacity	Sequential workload	Client workload
128GB	341	86
256GB	682	192
512GB	1364	361
1TB	2727	803

### \* Note:

- 1. Sequential: Mainly sequential write are estimated by PassMark Burnin Test v8.1 pro.
- 2. Client: Follow JESD218 Test method and JESD219A Workload, tested by ULINK. (The capacity lower than 64GB client workload is not specified in JEDEC219A, the values are estimated.)
- 3. Based on out-of-box performance.

### 2.8 Transfer Mode

CFexpress 3TE8 support following transfer mode:

PCIe Gen 3: 2 GB/s PCIe Gen 2: 1 GB/s PCIe Gen 1: 500 MB/s



### 2.9 Pin Assignment

Innodisk CFexpress 3TE8 follows CFexpress 1.0 type B pinout define. See Table 10 for CFexpress 3TE8 pin assignment.

Table 10: Innodisk CFexpress 3TE8 Pin Assignment

Pin No.	Signal #	I/O
21	GND	
20	PETp0	I
19	PETn0	I
18	GND	
17	PERp0	0
16	PERn0	0
15	GND	
14	REFCLK+	I
13	REFCLK-	I
12	INS#	0
11	CLKREQ#	0
10	+3.3V	
9	PERST#	I
8	Reserved (Optional for SMBus data)	I
7	Reserved (Optional for SMBus CLK)	I
6	PETp1	I
5	PETn1	I
4	GND	
3	PERp1	0
2	PERn1	0
1	GND	



### 2.10 Mechanical Dimensions

### CFexpress Type B

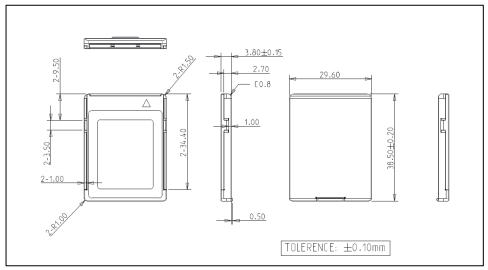


Figure 2: Innodisk CFexpress 3TE8 Mechanical Drawing

### CFexpress Type B with WP switch

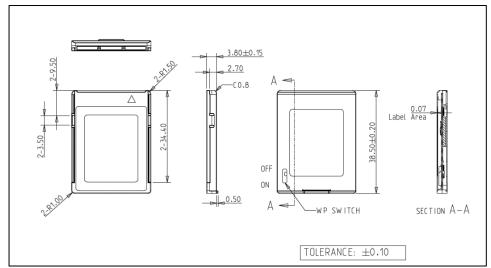


Figure 3: Innodisk CFexpress 3TE8 with WP switch Mechanical Drawing

### 2.11 Assembly Weight

An Innodisk CFexpress 3TE8 within NAND flash ICs, 128GB's weight is 14 grams approximately.

### 2.12 Seek Time

Innodisk CFexpress 3TE8 is not of magnetic rotating design. There is no seek or rotational latency.

### 2.13 NAND Flash Memory

Innodisk CFexpress 3TE8 uses industrial 3D TLC NAND flash memory, which is non-volatility, high reliability and high speed memory storage.



# 3. Theory of Operation

### 3.1 Overview

Figure 4 shows the operation of Innodisk CFexpress 3TE8 from the system level, including the major hardware blocks.

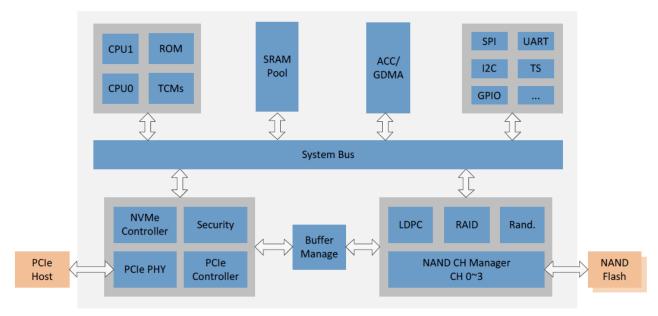


Figure 4: Innodisk CFexpress 3TE8 Block Diagram

Innodisk CFexpress 3TE8 integrates a PCIe Gen 3 x2 controller and NAND flash memories. Communication with the host occurs through the host interface, using the standard NVM protocol. Communication with the flash device(s) occurs through the flash interface.

### 3.2 PCIe Gen 3 x2 Controller

Innodisk CFexpress 3TE8 is designed with innodisk ID310, a PCIe Gen 3 x2 controller which is compliant with NVMe 1.4, up to 32.0Gbps transfer speed. In addition, it is compliant with PCIe Gen 1, Gen 2 and Gen 3 specification. The controller supports up to four channels for flash interface.

### 3.3 Error Detection and Correction

Innodisk CFexpress 3TE8 is designed with hardware LDPC ECC engine with hard-decision and soft-decision decoding. Low-density parity-check (LDPC) codes have excellent error correcting performance close to the Shannon limit when decoded with the belief-propagation (BP) algorithm using soft-decision information.



### 3.4 Wear-Leveling

Flash memory can be erased with a limited number of cycles. This number is called the **erase cycle limit** or **write endurance limit** and is defined by the flash NAND vendor. The erase cycle limit applies to each individual erase block in the flash device.

Innodisk CFexpress 3TE8 uses a combination of two types of wear leveling- dynamic and static wear leveling- to distribute write cycling across an SSD and balance erase count of each block, thereby extending device lifetime.

### 3.5 Bad Blocks Management

Bad Blocks are blocks that contain one or more invalid bits whose reliability are not guaranteed. The Bad Blocks may be presented while the SSD is shipped, or may develop during the lifetime of the SSD. When a Bad Block is detected, it will be flagged as unusable block by firmware. The SSD implement Bad Blocks management that consists of Bad Blocks replacement and Error Correcting to avoid data error occurred. The functions will be enabled automatically to transfer data from Bad Blocks to spare blocks, and correct error bit.

### 3.6 Garbage Collection/TRIM

Garbage collection and TRIM technology is used to maintain data consistency and perform continual data cleansing on SSDs. It runs as a background process, freeing up valuable controller resources while sorting good data into available blocks, and deleting bad blocks. It also significantly reduces write operations to the drive, thereby increasing the SSD's speed and lifespan.

### 3.7 End to End Data Path Protection

End-to-end Data Path Protection that secures the data transmission between host system and NAND Flash. In the transmission path, no matter in or out, all buffer and storage implement Error Code Correction that optimizes the data integrity in the whole transmission of SSD.

### 3.8 Thermal Management

CFexpress 3TE8 has built-in thermal sensor which can detect environment temperature of SSD. In the meantime, firmware will monitor the thermal sensor to prevent any failure of overheating. During extreme temperature, firmware will adjust the data transfer behavior to maintain the SSD's reliable operation.

### 3.9 iDataGuard

Innodisk's iData Guard is a comprehensive data protection mechanism that functions before and after a sudden power outage to the SSD. Low-power detection terminates data writing before an abnormal power-off, while table-remapping after power-on deletes corrupt data and maintains data integrity. Innodisk's iData Guard provides effective power cycling management, preventing data stored in flash from degrading with use.



### 3.10 iPower Guard

iPower Guard technology is a set of preventive measures that protect the SSD in an unstable power supply environment. This comprehensive package comprises safeguards for startup and shutdown to maintain device performance and ensure data integrity.

### 3.11 Thermal Throttling

Thermal throttling is a protective mechanism designed to safeguard components from potential damage caused by excessive temperatures. When an SSD approaches a critical temperature threshold, Innodisk firmware activates the thermal throttling mechanism to regulate the SSD's temperature. Thermal throttling is crucial for SSDs since it prevents drive damage, which could otherwise result in data loss. However, it's worth noting that when thermal throttling is activated, read and write tasks may experience a reduction in speed.

### 3.12 TCG OPAL

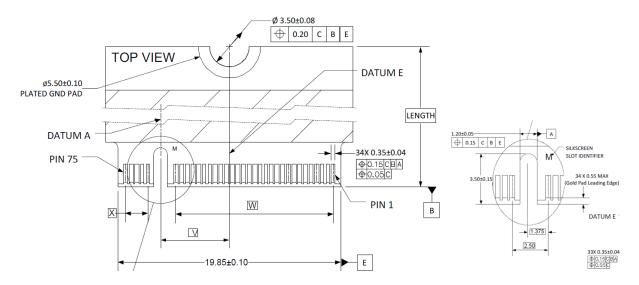
OPAL is a set of specifications for features of data storage devices that enhance security. These specifications are published by the Trusted Computing Group's Storage Work Group. Innodisk 3TE8 is compliant with TCG OPAL 2.0(\*1). The capability of TCG OPAL Security mode allows multiple users with independent access control to read/write/erase independent data areas (LBA ranges). Each locking range adjusts by authenticated authority. Note that by default there is a single "Global Range" that encompasses the whole user data area. In TCG Opal Security Mode, Revert, Revert SP and GenKey command can erase all of data including global range and locking range; in the meantime generate the new encrypted key.

\*1. You need to install TCG OPAL software to implement OPAL function, which is supplied by TCG OPAL software developed company



# 4. Installation Requirements

### 4.1 CFexpress 3TE8 Pin Directions



**Figure 5: Signal Segment and Power Segment** 

### 4.2 Electrical Connections for CFexpress 3TE8

CFexpress 4TE3 is PCIe interface; it follows CFexpress 1.0 type B pin assignment. For pin define please refer to 2.9 Pin Assignment.

### 4.3 Device Drive

CFexpress 3TE8 is compliant with NVMe 1.4. Both Operation System and BIOS should include NVMe driver to compatible with NVMe device. Nowadays, most of OS includes NVMe in-box driver now. For more information about the driver support in each OS, please visit the website <a href="https://nvmexpress.org/drivers/">https://nvmexpress.org/drivers/</a>. For BIOS NVMe driver support please contact with motherboard manufacturers.



# 5. SMART / Health Information

This log page is used to provide SMART and general health information. The information provided is over the life of the controller and is retained across power cycles. More details about Set Features command; please refer to NVM Express 1.4

### 5.1 Get Log Page (Log Identifier 02h)

Innodisk 3TE8 series SMART / Health Information Log are listed in following table.

Table 11: Get Log Page - SMART / Health Information Log

tes	Description		
	Critical Warning: This field indicates critical warnings for the state of the controller. Ea		
	corresponds	s to a critical warning type; multiple bits may be set to `1'. If a bit is cleared to `0	
	then that cr	itical warning does not apply. Critical warnings may result in an asynchronous eve	
	notification	to the host. Bits in this field represent the state at the time the Get Log Page	
	command is	s processed and may not reflect the state at the time a related asynchronous eve	
	notification,	, if any, occurs or occurred.	
	Bit	Definition	
	0	If set to `1', then the available spare capacity has fallen below the	
		threshold.	
	1	If set to `1', then a temperature is:	
		a) greater than or equal to an over temperature threshold.	
0		b) less than or equal to an under temperature threshold.	
	2	If set to `1', then the NVM subsystem reliability has been degraded due to	
		significant media related errors or any internal error that degrades NVM	
		subsystem reliability.	
	3	If set to '1', then all of the media has been placed in read only mode. The	
		controller shall not set this bit to '1' if the read-only condition on the media	
		is a result of a change in the write protection state of a namespace.	
	4	If set to '1', then the volatile memory backup device has failed. This field is	
		only valid if the controller has a volatile memory backup solution.	
	5	If set to `1', then the Persistent Memory Region has become read-only or	
		unreliable.	
	7:6	Reserved	
	1.1		



	Composite Ter	nperature: Contains a value corresponding to a temperature in degrees Kelvin		
	that represents the current composite temperature of the controller and namespace(s)			
	associated with that controller. The manner in which this value is computed is implementation			
1:2	specific and may not represent the actual temperature of any physical point in the NVM			
	subsystem. The value of this field may be used to trigger an asynchronous event.			
	Warning and cri	tical overheating composite temperature threshold values are reported by the		
	WCTEMP and CCTEMP fields in the Identify Controller data structure.			
2	Available Spar	re: Contains a normalized percentage (0 to 100%) of the remaining spare		
3	capacity availab	le.		
	Available Spar	e Threshold: When the Available Spare falls below the threshold indicated in		
4	this field, an asy	nchronous event completion may occur. The value is indicated as a normalized		
	percentage (0 to	o 100%). The values 101 to 255 are reserved.		
	Percentage Us	ed: Contains a vendor specific estimate of the percentage of NVM subsystem life		
	used based on t	he actual usage and the manufacturer's prediction of NVM life. A value of 100		
	indicates that th	e estimated endurance of the NVM in the NVM subsystem has been consumed,		
5	but may not indi	cate an NVM subsystem failure. The value is allowed to exceed 100. Percentages		
	greater than 254 shall be represented as 255. This value shall be updated once per power-on			
	hour (when the controller is not in a sleep state).			
	Refer to the JEDEC JESD218A standard for SSD device life and endurance measurement			
	techniques.			
	Endurance Gro	oup Critical Warning Summary: This field indicates critical warnings for the		
	state of Endurance Groups. Each bit corresponds to a critical warning type, multiple bits may be			
	set to `1'. If a bit is cleared to `0', then that critical warning does not apply to any Endurance			
	Group. Critical warnings may result in an asynchronous event notification to the host. Bits in this			
	field represent t	he current associated state and are not persistent.		
	If a bit is set to	1' in one or more Endurance Groups, then the corresponding bit shall be set to		
	`1' in this field.			
	Bit	Definition		
6	0	If set to `1', then the available spare capacity of one or more Endurance		
		Groups has fallen below the threshold.		
	1	Reserved		
	2	If set to `1', then the reliability of one or more Endurance Groups has been		
		degraded due to significant media related errors or any internal error that		
		degrades NVM subsystem reliability.		
	3	If set to `1', then the namespaces in one or more Endurance Groups have		
		been placed in read only mode not as a result of a change in the write		
		protection state of a namespace.		
	7:4	Reserved		



7:31	Reserved
	<b>Data Units Read:</b> Contains the number of 512 byte data units the host has read from the controller as part of processing a SMART Data Units Read Command; this value does not include metadata. This value is reported in thousands (i.e., a value of 1 corresponds to 1,000 units of
	512 bytes read) and is rounded up (e.g., one indicates that the number of 512 byte data units
32:47	read is from 1 to 1,000, three indicates that the number of 512 byte data units read is from
	2,001 to 3,000).
	Refer to the specific I/O Command Set specification for the list of SMART Data Units Read
	Commands that affect this field.
	A value of 0h in this field indicates that the number of SMART Data Units Read is not reported.
	Data Units Written: Contains the number of 512 byte data units the host has written to the
	controller as part of processing a User Data Out Command; this value does not include
	metadata. This value is reported in thousands (i.e., a value of 1 corresponds to 1,000 units of
	512 bytes written) and is rounded up (e.g., one indicates that the number of 512 byte data units
48:63	written is from 1 to 1,000, three indicates that the number of 512 byte data units written is from
	2,001 to 3,000).
	Refer to the specific I/O Command Set specification for the list of User Data Out Commands that
	affect this field.
	A value of 0h in this field indicates that the number of Data Units Written is not reported.
	Host Read Commands: Contains the number of SMART Host Read Commands completed by
64:79	the controller.
01173	Refer to the specific I/O Command Set specification for the list of SMART Host Read Commands
	that affect this field.
	<b>Host Write Commands:</b> Contains the number of User Data Out Commands completed by the
80:95	controller.
	Refer to the specific I/O Command Set specification for the list of User Data Out Commands that
	affect this field.
	<b>Controller Busy Time:</b> Contains the amount of time the controller is busy with I/O commands.
	The controller is busy when there is a command outstanding to an I/O Queue (specifically, a
96:111	command was issued via an I/O Submission Queue Tail doorbell write and the corresponding
	completion queue entry has not been posted yet to the associated I/O Completion Queue). This
	value is reported in minutes.
112:127	Power Cycles: Contains the number of power cycles.
128:143	<b>Power On Hours:</b> Contains the number of power-on hours. This may not include time that the
	controller was powered and in a non-operational power state.
144:159	<b>Unsafe Shutdowns:</b> Contains the number of unsafe shutdowns. This count is incremented
	when the controller does not report it is safe to power down prior to loss of main power.



	Media and Data Integrity Errors: Contains the number of occurrences where the controller
	detected an unrecovered data integrity error. Errors such as uncorrectable ECC, CRC checksum
160:175	failure, or LBA tag mismatch are included in this field. Errors introduced as a result of a Write
	Uncorrectable command (refer to the NVM Command Set Specification) may or may not be
	included in this field.
176:191	Number of Error Information Log Entries: Contains the number of Error Information log
170.131	entries over the life of the controller.
	Warning Composite Temperature Time: Contains the amount of time in minutes that the
	controller is operational and the Composite Temperature is greater than or equal to the Warning
192:195	Composite Temperature Threshold (WCTEMP) field and less than the Critical Composite
192.193	Temperature Threshold (CCTEMP) field in the Identify Controller data structure in Figure 275.
	If the value of the WCTEMP or CCTEMP field is 0h, then this field is always cleared to 0h
	regardless of the Composite Temperature value.
	Critical Composite Temperature Time: Contains the amount of time in minutes that the
	controller is operational and the Composite Temperature is greater than or equal to the Critical
196:199	Composite Temperature Threshold (CCTEMP) field in the Identify Controller data structure.
	If the value of the CCTEMP field is 0h, then this field is always cleared to 0h regardless of the
	Composite Temperature value.
200:201	<b>Temperature Sensor 1:</b> Contains the current temperature reported by the embedded thermal
	sensor in the controller.
202:203	<b>Temperature Sensor 2:</b> Contains the current temperature reported by the embedded thermal
	sensor in the NAND Flash (Channel #0 and CE #0).
204:205	<b>Temperature Sensor 3:</b> Contains the current temperature reported by the embedded thermal
	sensor in the NAND Flash (Channel #0 and CE #0).
206:207	<b>Temperature Sensor 4:</b> Contains the current temperature reported by the embedded thermal
	sensor in the NAND Flash (Last channel and CE #0).
208:209	<b>Temperature Sensor 5:</b> Contains the current temperature reported by temperature sensor 5.
210:211	<b>Temperature Sensor 6:</b> Contains the current temperature reported by temperature sensor 6.
212:213	<b>Temperature Sensor 7:</b> Contains the current temperature reported by temperature sensor 7.
214:215	<b>Temperature Sensor 8:</b> Contains the current temperature reported by temperature sensor 8.
	Thermal Management Temperature 1 Transition Count: Contains the number of times the
216:219	controller transitioned to lower power active power states or performed vendor specific thermal
210.213	management actions while minimizing the impact on performance in order to attempt to reduce
	the Composite Temperature because of the host controlled thermal management feature.
	<b>Thermal Management Temperature 2 Transition Count:</b> Contains the number of times the
	controller transitioned to lower power active power states or performed vendor specific thermal
220:223	management actions regardless of the impact on performance (e.g., heavy throttling) in order
	to attempt to reduce the Composite Temperature because of the host controlled thermal
	management feature.



	<b>Total Time For Thermal Management Temperature 1:</b> Contains the number of seconds that											
224:227	the controller had transitioned to lower power active power states or performed vendor specific											
	thermal management actions while minimizing the impact on performance in order to attempt to											
	reduce the Composite Temperature because of the host controlled thermal management											
	feature.											
	<b>Total Time For Thermal Management Temperature 2:</b> Contains the number of seconds tha											
228:231	the controller had transitioned to lower power active power states or performed vendor specific											
	thermal management actions regardless of the impact on performance (e.g., heavy throttling)											
	in order to attempt to reduce the Composite Temperature because of the host controlled thermal											
	management feature.											
232:337	Reserved											
338:345	Later Bad Count											
346:353	Power-On hours Count											
354:361	Drive Power Cycle Count											
362:369	Total Bad Block Count											
370:377	User Max Erase Count											
378:385	User Avg Erase Count											
386:393	Device Life											
394:401	Spare Block Count											
402:409	Program Fail Count											
410:417	Erase Fail Count											
418:425	Unexpected Power Loss Count											
426:433	Temperature ( Kelvin - K °K)											
434:441	Flash ID											
442:449	Later Bad Block Info (Read / Write / Erase)											
450:457	Total LBAs Written (unit = 32MB)											
458:465	Total LBAs Read (unit = 32MB)											



# 6. Part Number Rule

CODE	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21		
CODE	D	E	C	F	X	1	A	2	8	D	S	2	K	C	A	D	F	(W)	-	X	X		
									tior	)													
Code 1 <sup>st</sup> (Disk)											Code 14 <sup>th</sup> (Operation Temperature)												
D : Disk											C: Standard Grade ( $0^{\circ}$ ~ +70 $^{\circ}$ )												
Code 2 <sup>nd</sup> (Feature set)											Code 15 <sup>th</sup> (Internal control)												
E : Embedded series											A~Z: BGA PCB version.												
	Code 3 <sup>rd</sup> ~5 <sup>th</sup> (Form factor)											Code 16 <sup>th</sup> (Channel of data transfer)											
CFX: C	CFX: CFexpress type B											D: Dual Channels											
										Q	Q: Quad Channels												
			-	_																			
			de 7 <sup>t</sup>	<sup>th</sup> ∼9	th (C	apac	ity)				Code 17 <sup>th</sup> (Flash Type)												
A28: 1	28GE	3								F	F: Kioxia 3D TLC												
B56: 256GB																							
C12: 5	12GE	3																					
01T: 1	ГВ																						
		?d .	1 Oth		2th / C								Cl-	1 Oti	1.40-		-1 -		- \				
Code 10 <sup>th</sup> ~12 <sup>th</sup> (Controller)										Code 18 <sup>th</sup> (Optional Function) W: Write Protect Switch													
DS2: PCIe 3TE8 series with TCG OPAL function									V	v: Wr	ite Pi	rotec	t Sw	itch									
	Code 13 <sup>th</sup> (Flash mode)										Code 20 <sup>th</sup> ∼ (Customize code)												
K: 112 Layers 3D TLC																							